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# Search for a quantum critical end-point in $\text{CeRu}_2(\text{Si}_{1-x}\text{Ge}_x)_2$

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## Abstract

We use high-resolution dilatometry and electrical resistivity down to 20 mK and millitesla magnetic field steps to search for a possible quantum critical (end-) point (QC(E)P) in  $\text{CeRu}_2(\text{Si}_{1-x}\text{Ge}_x)_2$  with  $x = 0.00$  and  $0.02$  at the metamagnetic transition (MMT),  $B_m = 7.8$  and  $6.8$  T, respectively. We do not find any evidence for QCEP since (i) the peak height and FWHM of the magnetostrictive anomaly saturate below  $0.2$  K and (ii) the thermal expansion and the electrical resistivity indicate the formation of a Landau–Fermi liquid (LFL) state below  $0.3$  K even at  $B = B_m$ . We speculate that the metamagnetic crossover represents a Fermi surface reconstruction that is fully completed below  $0.2$  K.

**Keywords:**  $\text{CeRu}_2(\text{Si}_{1-x}\text{Ge}_x)_2$ ; Heavy fermion; Metamagnetism; Quantum critical end-point

Due to the great interest in itinerant electron metamagnetism and its putative quantum critical (end-) point (QC(E)P), exhibited by a variety of different materials (MnSi [1],  $\text{URu}_2\text{Si}_2$  [2],  $\text{Sr}_3\text{Ru}_2\text{O}_7$  [3]), there has been a “resurrection” of the  $\text{CeRu}_2\text{Si}_2$  [4] system. This prototype 4f heavy-fermion compound, long known to exhibit a metamagnetic transition associated with large changes in both Fermi surface and magnetism at

$7.8$  T, has been proposed as a direct analogue to the above materials [4]. If valid, the low-temperature properties should display the characteristics of a QCP, i.e., diverging experimental and non-Fermi liquid (NFL) behavior or the formation of novel phases.

In this work we determine, systematically and on an ultrafine field scale, the magnetostriction, thermal expansion and resistivity in a narrow field interval spanning the metamagnetic transition down to 20 mK on  $\text{CeRu}_2(\text{Si}_{1-x}\text{Ge}_x)_2$  with  $x = 0.00$  and  $0.02$ . The single crystal samples were grown by travelling floating zone for  $x = 0.00$  and

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the tri-arc Czochralski method for  $x = 0.02$ . Residual resistivities (RR) are very similar: 1.6 and  $1.8 \mu\Omega\text{cm}$  with RR ratios 43 and 37, respectively. Length changes and resistivity were detected utilizing a high resolution capacitive dilatometer and an AC four-point probe, both adapted to a dilution cryostat reaching 15 mK at fields up to 18 T.

In the magnetostriction coefficient  $\lambda = (1/L)\partial\Delta L(T, B)/\partial B$  we observe a sharp anomaly at the metamagnetic transition (MMT) for both concentrations (Fig. 1). This maximum shifts for  $x = 0.02$  to 6.8 T and broadens. At lower temperatures the anomalies become sharper. However, below 0.2 K the peak height and the FWHM of the maxima saturate according to a  $T^2$  law (solid and dotted lines in the inset of Fig. 1). This means that there is no observable change of the MMT to a first-order or continuous phase transition with decreasing temperature.

In Fig. 2 the linear thermal expansion coefficient  $\alpha = (1/L)\partial\Delta L(T, B)/\partial T$  of the undoped system is shown for magnetic fields very close to the MMT. For temperatures below 0.3 K the coefficient  $\alpha$  displays a linear temperature dependence, thus

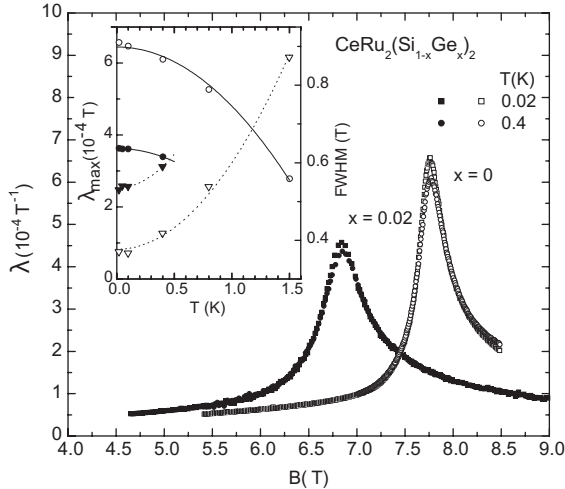


Fig. 1. Coefficient of linear magnetostriction  $\lambda$  along the  $c$ -axis of  $\text{CeRu}_2(\text{Si}_{1-x}\text{Ge}_x)_2$  for  $x = 0$  (open symbols) and  $x = 0.02$  (closed symbols) vs. magnetic field  $B||c$  at different temperatures. Inset displays temperature dependence of peak height  $\lambda_{\text{max}}$  (circles) and FWHM (triangles). Solid and dotted lines indicate  $T^2$  dependence and the saturation as  $T \rightarrow 0$ .

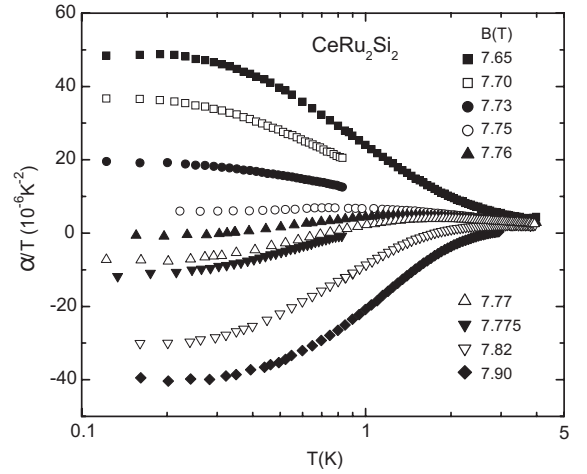


Fig. 2. Coefficient on linear thermal expansion  $\alpha$  as  $\alpha/T$  vs.  $T$  (logarithmic scale) at various magnetic fields  $B||c$  for  $\text{CeRu}_2\text{Si}_2$ .

$\alpha/T$  is constant—a hallmark of Landau–Fermi liquid (LFL) behavior. By fine-tuned magnetic fields we can demonstrate that  $\alpha$  changes continuously from large positive ( $B < B_m$ ) to large negative ( $B > B_m$ ) values and not suddenly as in previous publications [5,6]. The  $\alpha$ -coefficient in the doped system shows generally the same behavior (not displayed) but with about 40% smaller values.

The resistivity of  $\text{CeRu}_2(\text{Si}_{1-x}\text{Ge}_x)_2$  (Fig. 3) exhibits LFL behavior for both Ge concentrations (a)  $x = 0.00$  and (b)  $x = 0.02$ . Here the temperature-dependent part of the resistivity has a  $T^2$  behavior ( $\Delta\rho = AT^2$ ). The LFL region of  $\text{CeRu}_2\text{Si}_2$  is smaller ( $T \leq 0.3$  K) than that for the doped system ( $T \leq 0.5$  K). From the  $T \rightarrow 0$  intercept, the  $A$  coefficient can be determined which is a measure of the quasiparticle scattering cross section and proportional to the quasiparticle mass. For fields near the MMT (7.75, resp. 7 T in Fig. 3), the  $A$  coefficient increases in comparison to lower fields, but does not diverge; after the transition  $A$  decreases strongly (e.g. 8.1, resp. 7.5 T).

In conclusion, by studying the thermal expansion and resistivity of  $\text{CeRu}_2(\text{Si}_{1-x}\text{Ge}_x)_2$  it is not possible to tune the system from a MMT to a QCEP or even to a first-order phase transition. Thus a different tuning parameter would be needed. Yet, the pseudo-diverging behavior of

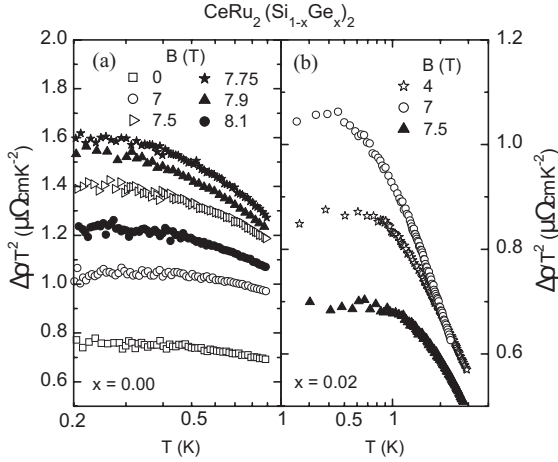


Fig. 3. Temperature dependent part of electrical resistivity  $\Delta\rho = \rho(T, B) - \rho_0(B)$  as  $\Delta\rho/T^2$  vs.  $T$  (logarithmic scale) for (a)  $\text{CeRu}_2\text{Si}_2$  and (b)  $\text{CeRu}_2(\text{Si}_{0.98}\text{Ge}_{0.02})_2$  at different magnetic fields  $B\parallel c$ .

$\text{CeRu}_2(\text{Si}_{1-x}\text{Ge}_x)_2$  at  $T \geq 0.5$  K misleadingly suggests that the system appears to be close to a QCP. From our experiments, the low temperature region

( $T \leq 0.3$  K) of the  $B$ - $T$  phase diagram clearly forms a LFL state in strong contrast to the other materials. This, we attributed to a Fermi surface reconstruction [7] that leads to spin polarization and a local-moment ferromagnetism above  $B_m$ .

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